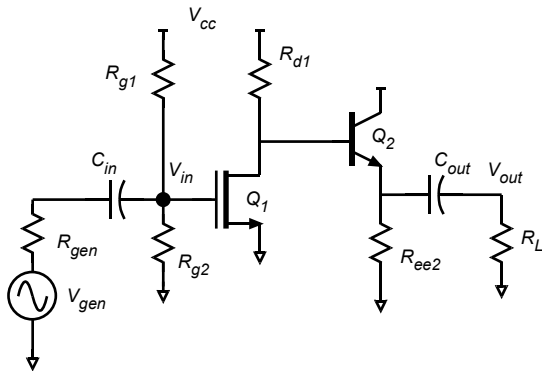


ECE137A Problem set #5

Problem 1



- Find all unspecified resistor values.
- Find the small signal gain and the input impedance of Q2
- Find the small signal gain and the input impedance of Q1.

The NMOSFET has

$$K_{\mu} = 10 \text{mA/V}^2 \cdot (W_g / 1\mu\text{m})$$

$$K_v = 2.0 \text{mA/V} \cdot (W_g / 1\mu\text{m})$$

$\Delta V = 100 \text{mV}$, $1/\lambda = 5$ Volts, and a 0.25V threshold.

Q2 : $\beta = 100$, $V_A = \text{infinity V}$

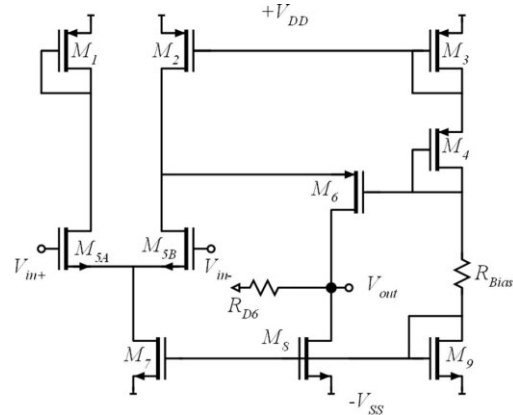
$+V_{cc} = +3.0$ volts. $R_{gen} = 100 \text{k}\Omega$

$R_L = 2 \text{k}\Omega$, $R_{g2} = 400 \text{k}\Omega$

Q1 is biased at 0.5mA drain current and $V_{gs} = 0.35 \text{V}$, Q2 is biased at 1mA collector current, and the emitter of Q2 is biased at 2.0V .

- Find the input impedance *** of the amplifier ****, V_{in}/V_{gen} , V_{out}/V_{in} , and V_{out}/V_{gen}

Problem 2



- find the small signal gain and input impedance of the M5AB differential pair.
- find the small signal gain and input impedance of M6.

The NMOSFETs have

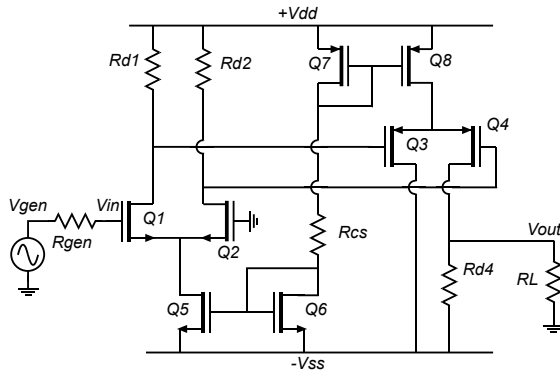
$$K_{\mu} = 10 \text{mA/V}^2 \cdot (W_g / 1\mu\text{m})$$

$$K_v = 2.0 \text{mA/V} \cdot (W_g / 1\mu\text{m})$$

$\Delta V = 100 \text{mV}$, $1/\lambda = 5$ Volts, and a 0.3V threshold. The PMOS FETs are the same, except have -0.3V threshold. All FETs are to operate with $|V_{gs}| = 0.35 \text{V}$, M5A, M5B, M3, and M6 are to operate with 25 microamps drain current. The supplies are $\pm 1 \text{V}$. The gates of M5A and M5B are at $+0.0 \text{V}$. V_{out} is zero volts. R_{D6} is $1 \text{M}\Omega$

- find all resistor values and FET widths.
- find the drain currents, and the drain, gate, and source voltages of all transistors
- find V_{in}/V_{gen} , V_{out}/V_{in} , and V_{out}/V_{gen} of the amplifier.
- find the maximum signal swing of the amplifier. This will involve finding the maximum signal swings of M5A, M6B, M6, and M8, and scaling each by the appropriate gains.

Problem 3



- (c) find the small signal gain of the differential pair Q3/Q4
 (d) find the small signal gain of the differential pair Q1/Q2. Note that because both outputs (the drains of both Q1 & Q2) are used, the gain is doubled.

The NMOSFETs have

$$K_{\mu} = 10 \text{mA/V}^2 \cdot (W_g / 1 \mu\text{m})$$

$$K_v = 2.0 \text{mA/V} \cdot (W_g / 1 \mu\text{m})$$

$\Delta V = 100 \text{mV}$, $1/\lambda = 5$ Volts, and a 0.25 V threshold. The PMOS FETs are the same, except have -0.25 V threshold. The FETs are to all operate at $|V_{gs}| = 0.30 \text{ V}$.

$I_{d5} = I_{d6} = I_{d7} = I_{d8} = 0.1 \text{ mA}$. The supplies are $\pm 1 \text{ V}$. $V_{d1} = V_{d2} = +0.3 \text{ V}$. $V_{out} = 0 \text{ V}$. $R_L = 5 \cdot R_{d4}$.

- (a) find all resistor values, all FET widths.
 (b) find the drain currents, and the drain, gate, and source voltages of all transistors
 (c) find V_{in}/V_{gen} , V_{out}/V_{in} , and V_{out}/V_{gen} of the amplifier.
 (d) Do not at this time find the maximum signal swings